Chapter 6 - BJTs

Threshold voltage: $V_T \approx 25.9 \text{ mV}$.

Two junctions in BJT, EBJ (Emitter Base Junction) and CBJ (Collector Base Junction).

Mode	EBJ	CBJ
Cutoff	Reverse	Reverse
Active	Forward	Reverse
Saturation	Forward	Forward

NPN TRANSISTOR:

In the cutoff mode:

$$V_{BC} < 0.4 \text{ V} \mid V_{BE} < 0.5 \text{ V} \mid$$

$$I_C = 0 \mid I_B = 0$$

In the active mode:

$$V_{BC} < 0.4 \text{ V} \mid V_{BE} \approx 0.7 \text{ V} \mid V_{CE} > 0.3 \text{ V}$$

$$I_C = \beta I_B \mid I_B > 0$$

In the saturation mode:

$$V_{BC} \approx 0.5 \text{ V} \mid V_{BE} \approx 0.7 \text{ V} \mid$$

 $V_{CE_{SAT}} \approx 0.2 \text{ V}$

$$I_C = \beta_{forced} I_B \mid I_B > 0$$

PNP TRANSISTOR:

In the cutoff mode:

$$V_{CB} < 0.4 \text{ V} \mid V_{EB} < 0.5 \text{ V} \mid$$

$$I_C = 0 \mid I_B = 0$$

In the active mode:

In the active mode:
$$i_C = I_C + \frac{I_C}{V_T} v_{be}$$

 $V_{CB} < 0.4 \text{ V} \mid V_{EB} \approx 0.7 \text{ V} \mid V_{EC} > 0.3 \text{ V}$ $i_C = I_C + i_c$
 $I_C = \beta I_B \mid I_B > 0$ $i_C = \frac{I_C}{V_T} v_{be}$

$$I_C = \beta I_B \mid I_B > 0$$

In the saturation mode:

$$V_{CB} \approx 0.5 \text{ V} \mid V_{EB} \approx 0.7 \text{ V} \mid i_c = g_m v_{be}$$

 $V_{EC_{SAT}} \approx 0.2 \text{ V}$

$$I_C = \beta_{forced} I_B \mid I_B > 0$$

Current relationships in a BJT transistor. I_S is known as Saturation Current $\vec{i_E} = i_C + i_B \mid i_E = \frac{\beta+1}{\beta} i_C \mid i_C = \alpha i_E \mid$

$\begin{array}{l} \alpha = \frac{\beta}{\beta+1} \mid \beta = \frac{\alpha}{1-\alpha} \\ \alpha \text{ is the common-base current gain.} \end{array}$

A BJT is in the Saturation Region if - The CBJ is Forward biased by more than 0.4V - The Ratio of i_C/i_B is lower than β

$$i_C = I_s e^{v_{BE}/V_T}$$

Considering the Early voltage

$$i_C = I_s e^{v_{BE}/V_T} \left(1 + \frac{v_{CE}}{V_A} \right)$$

$$r_o = \left[\frac{\delta i_c}{\delta v_{CE}} \Big|_{V_{BE} = \text{constant}} \right]^{-1}$$

$$r_o = \frac{V_A + V_{CE}}{I_C}$$

$$r_o = \frac{V_A}{I_C}$$

Where $I'_C = I_s e^{V_{BE}/V_T}$

$$R_{CE_{\mathrm{SAT}}} \equiv \frac{\delta v_{CE}}{\delta i_C} \Big|_{i_B = I_B | i_C = I_{C_{\mathrm{SAT}}}}$$

Amplifier stuff

$$v_{CE} = V_{CC} - i_C R_C$$

Operating point Q occurs at (V_{BE}, V_{CE}) .

$$A_v = -\left(\frac{I_C}{V_T}\right)R_C = -\frac{V_{RC}}{V_T}$$

$$V_{RC} = V_{CC} - V_{CE}$$

$$A_{vmax} \approx \frac{V_{CC}}{V_T}$$

Small signal stuff

$$i_C = I_C + \frac{I_C}{V_T} v_{bb}$$

$$i_C = I_C + i_c$$

$$i_a = a_m v_b$$

$$g_m = \frac{I_C}{V_T}$$

Base current:

$$i_B = \frac{i_C}{\beta} = \frac{I_C}{\beta} + \frac{1}{\beta} \frac{I_C}{V_T} v_{be}$$
 $i_B = I_B + i_b$

$$i_B = I_B + i_B$$

$$i_b = \frac{1}{\beta} \frac{IC}{V_T} v_b$$

We know that $I_C/V_T = g_m$ so

$$i_b = \frac{g_m}{\beta} v_{be}$$

The small-signal input resistance looking into the base, is denoted by r_{π} and is

$$r_{\pi} \equiv \frac{v_{be}}{i_b} = \frac{\beta}{g_m} = \frac{V_T}{I_B}$$

$$i_E = \frac{i_C}{\alpha} = \frac{I_C}{\alpha} + \frac{i_C}{\alpha}$$

$$i_E = I_E + i_E$$

$$i_E = \frac{i_C}{\alpha} = \frac{I_C}{\alpha} + \frac{i_c}{\alpha}$$

$$i_E = I_E + i_e$$

$$i_e = \frac{i_c}{\alpha} = \frac{I_C}{\alpha V_T} v_{be} = \frac{I_E}{V_T} v_{be}$$

Small-signal resistance looking into the emitter is

$$r_e \equiv \frac{v_{be}}{i_e}$$
 $r_e = V_T$

$$r_e = \frac{V_T}{I_E}$$
 $r_e = \frac{\alpha}{g_m} \approx \frac{1}{g_m}$

Relationship between r_{π} and r_{e} :

$$v_{be} = i_b r_\pi = i_e r_\pi$$

$$r_{\pi} = (i_e/i_b)r_e$$

$$r_{\pi} = (\beta + 1)r_e$$

Voltage gain of the amplifier:

$$A_v \equiv \frac{v_{ce}}{v_c} = -g_m R_0$$

$$A_v \equiv \frac{v_{ce}}{v_{be}} = -g_m R_C$$

$$A_v = -\frac{I_C R_C}{V_T}$$

Hybrid- π model includes the r_{π} resistor:

$$i_e = \frac{v_{be}}{r_{\pi}} + g_m v_{be}$$

$$\frac{v_{be}}{r_{\pi}} (1 + g_m r_{\pi})$$

$$\frac{v_{be}}{1+a}$$

$$\frac{1}{r_{\pi}}(1+g_m r_{\pi})$$
$$g_m v_{be} = g_m(i_b r_{\pi})$$

T-model includes the
$$r_e$$
 resistor:

$$g_m = I_C/V_T$$

$$r_e = \frac{V_T}{I_E} = \frac{\alpha}{g_m}$$

If we include r_o , the output voltage becomes:

$$v_o = -g_m v_{be}(R_C \parallel r_0)$$

Three different amplifier configurations:

Common-emitter

Common-base

Common-collector (also known as emitter follower)

But first, for all amplifier configurations:

$$R_{in} \equiv \frac{v}{i}$$

$$R_{in} \equiv \frac{v_i}{i_i}$$

$$v_i = \frac{R_{in}}{R_{in} + R_{sig}} v_{sig}$$

$$A_{vo} \equiv \frac{v_o}{v_i} \Big|_{R_L = \infty}$$

$$R_x = \frac{v_x}{i_x}$$

$$v_o = \frac{R_L}{R_L + R_o} A_{vo} v_i$$

$$v_o = \frac{R_L}{R_L + R_o} A_{vo} v_i$$

$$A_v \equiv \frac{v_o}{v_i} = A_{vo} \frac{R_L}{R_L + R_O}$$

$$G_v \equiv \frac{v_o}{v_{sig}}$$

$$G_v \equiv \frac{v_o}{v_{sig}}$$

$$G_v = \frac{R_{in}}{R_{in} + R_{sig}} A_v$$